M1MA151WK, M1MA152WK

Common Cathode Silicon Dual Switching Diodes

These Common Cathode Silicon Epitaxial Planar Dual Diodes are designed for use in ultra high speed switching applications. These devices are housed in the SC-59 package which is designed for low power surface mount applications.

Features

- Fast t_{rr} , < 3.0 ns
- Low C_D, < 2.0 pF
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Reverse Voltage M1MA151WK M1MA152WK	V _R	40 80	Vdc
Peak Reverse Voltage M1MA151WK M1MA152WK	V _{RM}	40 80	Vdc
Forward Current Single Dual	I _F	100 150	mAdc
Peak Forward Current Single Dual	I _{FM}	225 340	mAdc
Peak Forward Surge Current Single Dual	I _{FSM} (Note 1)	500 750	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation	P _D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. t = 1 sec



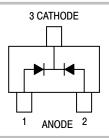
ON Semiconductor®

www.onsemi.com

SC-59 PACKAGE SINGLE SILICON SWITCHING DIODES 40 V/80 V 100 mA SURFACE MOUNT



SC-59 CASE 318D STYLE 3



MARKING DIAGRAM



Mx = Device Code

=T for 151

U for 152 M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
M1MA151WKT1G	SC-59 (Pb-Free)	3,000 / Tape & Reel
SM1MA151WKT1G	SC-59 (Pb-Free)	3,000 / Tape & Reel
M1MA152WKT1G	SC-59 (Pb-Free)	3,000 / Tape & Reel
NSVM1MA152WKT1G	SC-59 (Pb-Free)	3,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

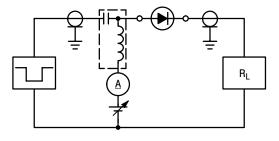
M1MA151WK, M1MA152WK

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Characteristic	Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Current M1MA151WK M1MA152WK	I _R	V _R = 35 V V _R = 75 V	<u>-</u>	0.1 0.1	μAdc
Forward Voltage	V _F	I _F = 100 mA	-	1.2	Vdc
Reverse Breakdown Voltage M1MA151WK M1MA152WK	V _R	I _R = 100 μA	40 80	-	Vdc
Diode Capacitance	C _D	V _R = 0, f = 1.0 MHz	-	2.0	pF
Reverse Recovery Time (Figure 1)	t _{rr} (Note 2)	$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V},$ $R_L = 100 \Omega, I_{rr} = 0.1 I_R$	-	3.0	ns

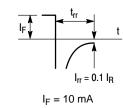
^{2.} t_{rr} Test Circuit

RECOVERY TIME EQUIVALENT TEST CIRCUIT



$t_p = 2 \mu s$ $t_p = 0.35 \text{ ns}$

INPUT PULSE



OUTPUT PULSE

 $I_F = 10 \text{ mA}$ $V_R = 6 \text{ V}$ $R_L = 100 \Omega$

Figure 1. Reverse Recovery Time Equivalent Test Circuit

M1MA151WK, M1MA152WK

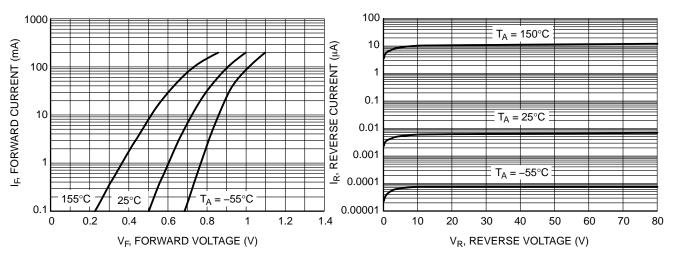


Figure 2. Forward Voltage

Figure 3. Reverse Leakage

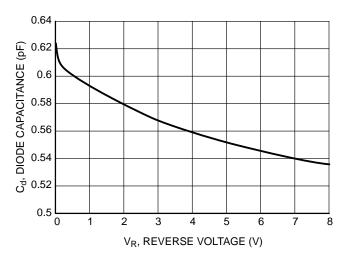


Figure 4. Diode Capacitance





SC-59-3 2.90x1.50x1.15, 1.90P CASE 318D **ISSUE J**

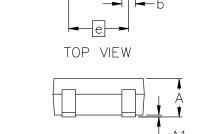
E1

DATE 15 FEB 2024

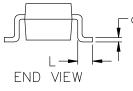
NOTES:

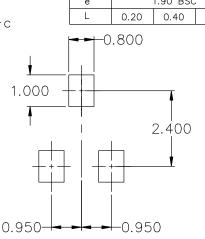
- DIMENSIONING AND TOLERANCING CONFORM TO ASME
- ALL DIMENSION ARE IN MILLIMETERS.

	MILLIMETERS		
DIM	MIN.	NOM.	MAX.
Α	1.00	1.15	1.30
A1	0.01	0.06	0.10
b	0.35	0.43	0.50
С	0.09	0.14	0.18
D	2.70	2.90	3.10
E	2.50	2.80	3.00
E1	1.30	1.50	1.70
е	1.90 BSC		
L	0.20	0.40	0.60



SIDE VIEW





GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

Μ = Date Code

= Pb-Free Package* (*Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may

not follow the Generic Marking.

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES

REFERENCE MANUAL, SOLDERRM/D.

RECOMMENDED MOUNTING FOOTPRINT*

STYLE 1: STYLE 2: STYLE 3: PIN 1. ANODE 2. N.C. PIN 1. BASE PIN 1. ANODE 2. EMITTER 2. ANODE 3. COLLECTOR 3. CATHODE

STYLE 4: STYLE 5: STYLE 6: PIN 1. CATHODE PIN 1. CATHODE PIN 1 ANODE 2. N.C. 3. ANODE 2. CATHODE 3. ANODE CATHODE 3. ANODE/CATHODE

DOCUMENT NUMBER:	98ASB42664B	Electronic versions are uncontrolled except when accessed directly from the Document Reportant Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-59-3 2.90x1.50x1.15. 1	.90P	PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales